



Fast Switching Diode

Features

- Silicon Epitaxial Planar Diodes
- Electrical data identical with the device 1N4154

Applications

Extreme fast switchess

Mechanical Data

Case: MiniMELF Glass Case (SOD-80)

Weight: approx. 30 mg Cathode Band Color: Black **Packaging Codes/Options:**

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box GS08 / 2.5 k per 7" reel (8 mm tape), 12.5 k/box



Parts Table

Part	Type differentiation	Ordering code	Remarks
LL4154	V _{RRM} = 35 V	LL4154-GS18 or LL4154-GS08	Tape and Reel

Absolute Maximum Ratings

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Repetitive peak reverse voltage		V _{RRM}	35	V	
Reverse voltage		V _R	25	V	
Peak forward surge current	t _p = 1 μs	I _{FSM}	2	Α	
Repetitive peak forward current		I _{FRM}	500	mA	
Forward current		I _F	300	mA	
Average forward current	V _R = 0	I _{FAV}	150	mA	
Power dissipation		P _V	500	mW	

Thermal Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Junction ambient	on PC board 50 mm x 50 mm x 1.6 mm	R_{thJA}	500	K/W
Junction temperature		T _j	175	°C
Storage temperature range		T _{stg}	- 65 to + 175	°C

Document Number 85560 www.vishay.com

Rev. 1.6, 06-Apr-04

Vishay Semiconductors



Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward voltage	I _F = 30 mA	V _F			1	V
Reverse current	V _R = 25 V	I _R			100	nA
	V _R = 25 V, T _j = 150 °C	I _R			100	μΑ
Breakdown voltage	$I_R = 5 \mu A, t_p/T = 0.01, t_p = 0.3 \text{ ms}$	V _(BR)	35			V
Diode capacitance	$V_R = 0, f = 1 \text{ MHz}, V_{HF} = 50 \text{ mV}$	C _D			4	pF
Reverse recovery time	$I_F = I_R = 10 \text{ mA}, i_R = 1 \text{mA}$	t _{rr}			4	ns
	$I_F = 10 \text{ mA}, V_R = 6 \text{ V},$ $I_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$	t _{rr}			2	ns

Typical Characteristics (T_{amb} = 25 °C unless otherwise specified)

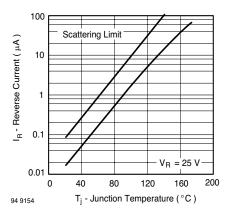


Fig. 1 Reverse Current vs. Junction Temperature

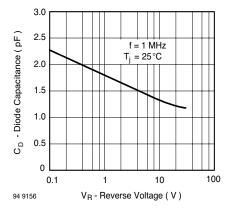


Fig. 3 Diode Capacitance vs. Reverse Voltage

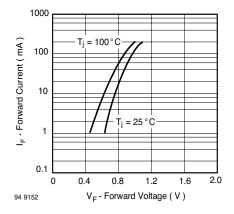
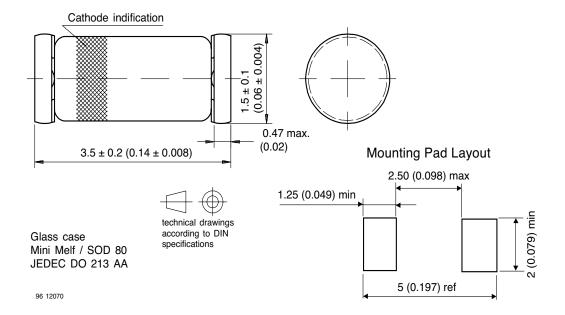


Fig. 2 Forward Current vs. Forward Voltage





Package Dimensions in mm (Inches)



Vishay Semiconductors



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

> Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423

Document Number 85560 Rev. 1.6, 06-Apr-04

Legal Disclaimer Notice



Vishay

Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.

Document Number: 91000 www.vishay.com
Revision: 08-Apr-05 1